

Agilent 4073B

Ultra Advanced Parametric Tester

Data Sheet



General Description

The Agilent 4073B Ultra Advanced Parametric Tester is the flagship of the 4070 Series. It is designed to perform fast and precise DC measurements, capacitance measurements, Flash memory cell tests, and other high-frequency applications. The system supports up to eight Source Monitor Units (SMUs). Each SMU is self-calibrating, and can be individually configured to force either current or voltage, as well as simultaneously measure either current or voltage. The system includes the High-Speed Capacitance Measurement Unit (HSCMU) that enables the measurement of capacitance and impedance with unprecedented speed. External instruments can be integrated into the system via

six auxiliary input ports or 48 extended path inputs. The extended path inputs allow the user to connect external signals directly to the DUT pins. A lowleakage switching matrix connects all of the inputs to fullyguarded Kelvin output pins, which are customizable from 12 to 48 pins. One special additional pin is dedicated as a chuck connection. The 4073B also has a high-frequency switching matrix with integrated pulse generator control. The high-frequency matrix is organized as two 3 24 matrices (six inputs in total), and 1 TO 2 furnished connectors may be used on each matrix pair to create one 3 ~ 48 matrix (three inputs in total). The system also has one 1.6 A ground unit.

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General Description(continued)

Measurement functions

DC Current, DC Voltage, Capacitance and Conductance, Impedance, Differential voltage and Pulse force.

DC Measurements

Spot, Sweep, Pulse Bias, and Pulse Sweep.

Measurement unit: HRSMU (High Resolution SMU), MPSMU (Medium Power SMU and HPSMU (High Power SMU) Measurement range: 10 fA¹ to 100 mA, 2 µV to 100 V (using the two low current SMU ports) 100 fA to 1 A², 2 µV to 200 V² (using the 6 standard SMU ports)

 1 Using HRSMU. Using MPSMU, 100 fA to 100 mA, 2 μV to 100 V

 2 Using optional HPSMU. Using MPSMU, 100 fA to 100 mA, 2 μV to 100 V

Capacitance/Conductance Measurements

C/G, C/G-V and C/G-V/f

Measurement unit: High Speed Capacitance Measurement Unit (HSCMU) Test Frequencies: 1 kHz - 2 MHz, 34 points (Measurement accuracies are guaranteed at the following frequency points: 1 kHz, 10 kHz, 100 kHz and 1 MHz) Measurement range: 1 fF to 100 nF, 0.1 nS to 7.5 mS DC Bias Voltage: ±10 V

Impedance Measurements

 Z/θ and Z/θ - f

Measurement unit: HSCMU Test Frequencies: 1 kHz - 2 MHz, 34 points DC Bias Voltage: ±10 V

Two Terminal Differential Voltage Measurements

Measurement Unit: Agilent 3458A Measurement range: 0.1 µV to 100 V

High Frequency Pulse Force

Supported pulse generators: Agilent 81110A and 8114A Maximum number of installable pulse generators: $5 \times 81110A$ (without 8114A) $4 \times 81110A$ (with $1 \times 8114A$) $2 \times 81110A$ (with $2 \times 8114A$) Pulse level (at open load): ±19 V (81110A), -49.9 V to + 50 V (8114A) Pulse period: 350 ns to 999 s (81110A) 350 ns to 999 ms (8114A) Pulse width: 50 ns to 999 ms (81110A) 150 ns to 150 ms (8114A) Pulse delay: 0 s to 998 ms Transition time: 20 ns to 200 ms (81110A) 65 ns (8114A)

Switching Matrix Measurement Pins

Between 12 and 48 pins

Note: One additional pin is dedicated for the prober chuck connection.

Switching Matrix Instrument Ports

Up to eight SMUs One ground unit (GNDU) Eight auxiliary (AUX) ports (Two ports are used for HSCMU) Six high frequency (HF) ports 48 extended paths Pulse switch input/output ports

Switching Matrix Subsystem

Maximum DUT Pins

48 output pins plus one pin for the prober chuck connection (triaxial connector). Only the E3122A (high-resolution pin board) can be used for the 4073B (The E3121A cannot be used).

Maximum Number of Instrument Ports

SMU Ports in Testhead (Eight SMUs + one GNDU): Two ports for low-current measurement (Non-Kelvin) Four ports (Kelvin) Two ports (Non-Kelvin) One port for GNDU (Kelvin)

Auxiliary (AUX) ports: Six for external instruments (Digital voltmeter, etc.) and two for HSCMU

2 triaxial input ports (Force/ Guard/Common, AUX ports 1 and 2)

Four BNC two-pair input ports (Force/Common and Sense/ Common, AUX ports 3 to 6) Two BNC input ports (Force/ Common, AUX ports 7 and 8, connected to HSCMU in default)

High Frequency (HF) ports: Six for pulse generator (81110A or 8114A) or other external instruments.

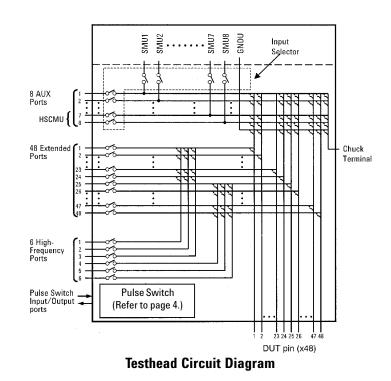
HF ports 1 through 3 can access measurement pins 1 through 24, and HF ports 4 through 6 can access measurement pins 25 through 48. The user has the option of connecting any of the following HF port pairs together via a 1 TO 2 ADAPTOR in order to access all (1 through 48) measurement pins: HF ports 1 and 4, HF ports 2 and 5, and HF ports 3 and 6. Extended path:

48 extended paths – The system provides one on/off relay for each path.

Pulse switch input/output ports: Please refer to page 4.

Maximum Voltage at Each Port

SMU port in Test Head: ±200 V AUX port:



±200 V (AUX ports 1 and 2) ±100 V (AUX ports 3 to 8)

HF port:

±100 V (between force and common of each HF port)

±100 V (between two of forces of all HF ports)

±100 V (between any force of HF ports and any force of extended paths)

Extended path:

±100 V (between force and common of each extended path)

±100 V (between any force of HF ports and any force of extended paths) Zero reference: ±200 mV

Maximum Current, Port to DUT

Pin

SMU port in Test Head:	±1.0 A
GNDU:	±1.6 A
AUX port:	±1.0 A
HF port:	±0.5 A
Extended path:	$\pm 0.5 \text{ A}$

Maximum Residual Resistance

Through AUX port Low current port: Force 1.0 Ω Kelvin port:

Force 1.0 Ω Sense 2.5 Ω

Non-Kelvin port: Force 1.0Ω Through HF port (supplemental characteristics): 2.0 Ω

Maximum Stray Capacitance between DUT Pins (supplemental characteristics) 3 pF

Isolation Resistance (supplemental characteristics)

Low Current (with Guard): $1 \times 10^{15} \Omega$

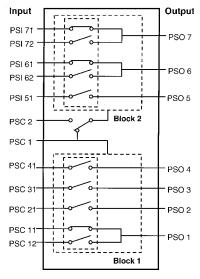
HF Port Bandwidth (@-3dB) (supplemental characteristics) 60 MHz (50 Ω load impedance: from port to DUT pin, 3×24 configuration)

HF Port Cross Talk Between Pins (supplemental characteristics)

 ± 2 % (5 k Ω load impedance: from port to DUT pin, 20 ns pulse transition time)

Pulse Switch

The pulse switch includes seven semiconductor switching relays, for reliable and direct control of pulse shaping by the pulse generator or CPU. The pulse switch is integrated into the 4073B test head.



Pulse Switch

Number of Blocks

Two blocks

Number of Switches of Each Block Block 1:

Three relays (make or break, selectable type) and 1 relay (transfer type to create multilevel pulse)

Block 2:

One relay (make or break, selectable type) and two relays (transfer type to create multilevel pulse)

Control Input Port

One input per each block (PSC1 and PSC2)

Control Method

Both the PG and CPU can control all switches. PG or CPU control is independent for every block. In the case of PG control, block 1 can be controlled by the PSC1 input, and block 2 can be controlled by either PSC1 or PSC2 (selectable).

Mode of Relay Control

Make or break, selectable type relay:

Normally open or Normally closed modes are selectable. Transfer type relay:

Normally open and Normally closed modes are not selectable.

Maximum Voltage

- ±60 V (between force and common of each switch)
- ±60 V (between PSI 21 and PSO 2, between PSI 31 and PSO
 - 3, between PSI 41 and PSO
 - 4, between PSI 51 and PSO
 - 5)

±60 V between PSI 11 (or PSI 12) and PSO 1, between PSI 11 and PSI 12, between PSI 61 (or PSI 62) and PSO 6, between PSI 61 and PSI 62, between PSI 71 (or PSI 72) and PSO 7, between PSI 71 and PSI

Maximum Current

72)

±0.4 A (from input to output)

Residual Resistance (supplemental characteristics)

Nominal 2 Ω (from IN to OUT)

OFF Capacitance (supplemental characteristics)

- 80 pF (between IN and OUT: Vin-Vout = 0 V)
- 100 pF (force <-> common @ output of make or break, selectable type relay: Vin-Vout = 0 V)

Operating Time of Switching (supplemental characteristics) Max. 2 ms

max. 2 ms

DC Measurement Subsystem: SMU (Source and Monitor Unit)

Voltage Source/Monitor Range, Resolution, and Accuracy using HRSMU

Full Scale Voltage Range	Force Resolution	Measure Resolution: High Speed	Measure Resolution: Precision	Measure Accuracy	Force Accuracy
±2 V	100 μV	100 μV	2 μV	a: 0.02% b: 0.025% c: Rmat × lo	a: 0.03% b: 0.035% c: Rmat × lo
±20 V	1 mV	1 mV	20 µV	a: 0.02%	a: 0.03%
±40 V	2 mV	2 mV	40 µV	b: 0.015%	b: 0.02%
±100 V	5 mV	5 mV	100 μV	c: Rmat × lo	c: Rmat × Io

Voltage Source/Monitor Range, Resolution, and Accuracy using MPSMU and HPSMU

Full Scale Voltage Range	Force Resolution	Measure Resolution: High Speed	Measure Resolution: Precision	Force Accuracy	Measure Accuracy
±2 V	100 µV	100 μV	2 μV		a: 0.040/
±20 V	1 mV	1 mV	20 μV	a: 0.05% b: 0.05%	a: 0.04% b: 0.04%
±40 V	2 mV	2 mV	40 µV		c: Rmat×lo
±100 V	5 mV	5 mV	100 µV	c: Rmat × lo	
±200 V ¹	10 mV	10 mV	200 μV		a: 0.045% b:0.04% c: Rmat × lo

Force Accuracy is calculated as follows:

 \pm (a % of output setting value + b% of output voltage range + c) (V)

Measure Accuracy is calculated as follows:

 $\pm(a \% \text{ of measure value} + b\% \text{ of measurement voltage range} + c) (V)$

Low Current Port (SMU1 and SMU2): 1.0 Ω

Kelvin Port: (SMU3 to SMU6); 3 m Ω Non-Kelvin Port (SMU7 and SMU8): 1.0 Ω

¹Using HPSMU

Current Source/Monitor Range, Resolution, and Accuracy using HRSMU connected to SMU1 and SMU2 ports

Full Scale Current Range	Force Resolution	Measure Resolution: High Speed	Measure Resolution: Precision	Force Accuracy	Measure Accuracy
±100 mA	5 μΑ	5 μΑ	100 nA	a:0.12 % b: 0.05 + 0.0001 × Vo % c: 0	a: 0.1 % b: 0.04 + 0.0001 × Vo % c: 0
±10 mA	500 nA	500 nA	10 nA	a: 0.06 % b: 0.04 + 0.0001 × Vo % c: 0	a: 0.06% b: 0.03 + 0.0001 × Vo % c: 0
±1 mA	50 nA	50 nA	1 nA	a: 0.06 % b: 0.05 + 0.0001 × Vo% c: 0	a: 0.06% b: 0.04 + 0.0001 × Vo % c: 0
±100 μA	5 nA	5 nA	100 pA	a: 0.07 % b: 0.04 + 0.0001 × Vo % c: 0	a: 0.06% b: 0.035 + 0.0001 × Vo % c: 0
±10 μΑ	500 pA	500 pA	10 pA	a: 0.07 % b: 0.05 + 0.0001 × Vo % c: 0	a: 0.06% b: 0.04 + 0.0001 × Vo % c: 0
±1 μA	50 pA	50 pA	1 pA	a: 0.12 % b: 0.04 + 0.0001 × Vo % c: 0	a: 0.12% b: 0.035 + 0.0001 × Vo % c: 0
±100 nA	5 pA	5 pA	100 fA	a: 0.12 % b: 0.05 + 0.0001 × Vo % c: 1 fA/V × Vo	a: 0.12% b: 0.04 + 0.0001 × Vo % c: 1 fA/V × Vo
±10 nA	500 fA	500 fA	10 fA	a: 1 % b: 0.05 + 0.0001 × Vo % c: 3 pA + 1 fA/V × Vo	a: 1% b: 0.04 + 0.0001 × Vo % c: 3 pA + 1 fA/V × Vo
±1 nA	50 fA	50 fA	10 fA	a: 1% b: 0.07 + 0.0001 × Vo % c: 3 pA + 1 fA/V × Vo	a: 1% b: 0.04 + 0.0001 × Vo % c: 3 pA + 1 fA/V × Vo
±100 pA	5 fA	5 fA	2 fA	a: 4 % b: 0.4 + 0.0001 × Vo % c: 500 fA + 1 fA/V × Vo	a: 4% b: 0.12 + 0.0001 × Vo % c: 500 fA + 1 fA/V × Vo
±10 pA	1 fA	2 fA	1 fA	a: 4 % b: 4.0 + 0.0001 × Vo % c: 500 fA + 1 fA/V × Vo	a: 4% b: 1.0 + 0.0001 × Vo % c: 500 fA + 1 fA/V × Vo

DC Measurement Subsystem (continued)

Full Scale Current Range	Force Resolution	Measure Resolution: High Speed	Measure Resolution: Precision	Force Accuracy	Measure Accuracy
±100 mA	5 μΑ	5 µA	100 nA		
±10 mA	500 nA	500 nA	10 nA	a: 0.12%	a: 0.1%
±1 mA	50 nA	50 nA	1 nA	a. 0.12% b: 0.1 + 0.0005×Vo %	b: 0.05 + 0.0005 × Vo %
±100 μA	5 nA	5 nA	100 pA	c: 0	c: 0
±10 μA	500 pA	500 pA	10 pA		
±1 μA	50 pA	50 pA	1 pA	a: 0.2%	a: 0.2%
±100 nA	5 pA	5 pA	100 fA		b: 0.05 + 0.0005 × Vo % c: 0.02 pA/V ′ Vo
±10 nA	500 fA	500 fA	10 fA	a: 1% b: 0.1 + 0.0005 × Vo %	a: 1%
±1 nA	50 fA	50 fA	10 fA	c: 3 pA + 0.02 pA/V ′ Vo	b: 0.1 + 0.0005 × Vo % c: 3 pA + 0.02 pA/V × Vo

Current Source/Monitor Range, Resolution, and Accuracy using MPSMU connected to SMU1 and SMU2 ports

Note: The HPSMU cannot be connected to SMU1 and SMU2 ports.

Current measurement ccuracy of the SMU may be affected by elecromagnetic field strength over 3 V/m at a frequency of 26 MHz to 1 GHz.

Current Source/Monitor Range, Resolution, and Accuracy using an MPSMU or HPSMU connected to the SMU3 through SMU8 ports

Full Scale Current Range	Force Resolution	Measure Resolution: High Speed	Measure Resolution: Precision	Force Accuracy	Measure Accuracy
±1 A ¹	50 µA	50 µA	1 μΑ	a: 0.5 % b: 0.1 + 0.0005 × Vo% c: 0	a: 0.5 % b: 0.05 + 0.0005 × Vo % c: 0
±100 mA	5 µA	5 μΑ	100 nA		
±10 mA	500 nA	500 nA	10 nA	a: 0.12 % b: 0.1 + 0.0005 × Vo % c: 0 a: 0.1 % b: 0.05 + 0.00 c: 0	
±1 mA	50 nA	50 nA	1 nA		a: 0.1 % b: 0.05 + 0.0005 × Vo %
±100 μA	5 nA	5 nA	100 pA		
±10 μΑ	500 pA	500 pA	10 pA		
±1μA	50 pA	50 pA	1 pA		a: 0.2 % b: 0.05 + 0.0005 × Vo %
±100 nA	5 pA	5 pA	100 fA		c: 300 pA + 10 pA/V × Vo
±10 nA ²	500 fA	500 fA	10 fA	a: 1% b: 0.1 + 0.0005 × Vo %	a: 1 % b: 0.1 + 0.0005 × Vo %
±1 nA ²	50 fA	50 fA	10 fA	c: 303 pA + 10 pA/V × Vo	c: 303 pA + 10 pA/V × Vo

Force Accuracy is calculated as follows: ±(a % of output setting value + b% of output current range + c) (A)

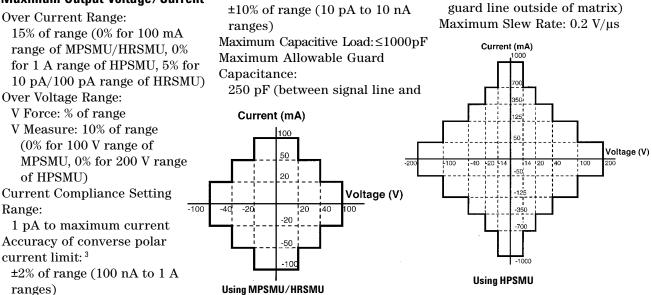
Measure Accuracy is calculated as follows: $\pm(a \% of measured value + b\% of current measurement range + c) (A)$

Note: The HPSMU cannot be connected only to SMU3 and SMU4 ports. It can be connected only to SMU3 and SMU4 ports.

Note: Current measurement ccuracy of the SMU may be affected by elecromagnetic field strength over 3 V/m at a frequency of 26 MHz to 1 GHz. ¹ Using HPSMU, ² Suplemental characteristics when using SMU3 and SMU4 ports

Vo = Output voltage

Maximum Output Voltage/Current



SMU configuration

Minimum configuration:

One HRSMU and two MPSMUs (default configuration)

A maximum of two HRSMUs can be installed and connected only to the SMU1 and SMU2 ports. A maximum of two HPSMUs can be installed and connected only to the SMU3 and SMU4 ports. The first HPSMU must be connected to SMU3 and the second to SMU4. The default configuration of the 4073B has one HRSMU (connected to the SMU2 port) and two MPSMUs (connected to the SMU3 and SMU4 ports). The following tables indicate the installation order for additional SMUs.

One HRSMU and no HPSMU installed in addition to MPSMUs

Port Number	Installed SMU	Installation order for additional SMUs
1	MPSMU	2
2	MPSMU	Default
3	HRSMU	Default
4	MPSMU	Default
5	MPSMU	1
6	MPSMU	3
7	MPSMU	4
8	MPSMU	5

Two HRSMU and one HPSMU installed in addition to MPSMUs

Port Number	Installed SMU	Installation order for additional SMUs
1	MPSMU	1
2	HRSMU	Default
3	HPSMU	Optiona HPSMU
4	MPSMU	Default
5	MPSMU	Default
6	MPSMU	2
7	MPSMU	3
8	MPSMU	4

Two HRSMUs and no HPSMUs installed in addition to MPSMUs

Port Number	Installed SMU	Installation order for additional SMUs
1	HRSMU	Optional HRSMU
2	HRSMU	Default
3	MPSMU	Default
4	MPSMU	Default
5	MPSMU	1
6	MPSMU	2
7	MPSMU	4
8	MPSMU	5

Two HRSMUs and one HPSMU installed in addition to MPSMUs

Port Number	Installed SMU	Installation order for additional SMUs
1	HRSMU	Optional HRSMU
2	HRSMU	Default
3	HPSMU	Optional HPSMU
4	MPSMU	Default
5	MPSMU	Default
6	MPSMU	1
7	MPSMU	2

One HRSMU and two HPSMUs installed in addition to MPSMUs

Port Number	Installed SMU	Installation order for additional SMUs
1	MPSMU	Default
2	HRSMU	Default
3	HPSMU	Optional HPSMU
4	HPSMU	Optional HPSMU
5	MPSMU	Default
6	MPSMU	1
7	MPSMU	2

Two HRSMUs and two HPSMUs installed in addition to MPSMUs

Installed SMU	Installation order for additional SMUs
HRSMU	Optional HRSMU
HRSMU	Default
HPSMU	Optional HPSMU
HPSMU	Optional HPSMU
MPSMU	Default
MPSMU	Default
	SMU HRSMU HRSMU HPSMU HPSMU MPSMU

DC Mearurement Subsystem: Ground Unit (GNDU)

This unit is used for ground when making measurements.

Output Voltage: 0 V Maximum Current: ±1.6 A Offset Voltage: ±200 µV Maximum Capacitance Load (Supplemental Charactaristics): 1 µF

DC Measurement Subsystem: Digital Volt Meter (Agilent 3458A) Voltage Measurement Range,

Resolution, and Accuracyv(at number of Power Line Cycles ≥ 1)

Full-Scale		Accuracy
Voltage Range	Resolution	(% of reading + volt)
0.1 V	0.1 µV	0.01% + 100 μV
1 V	1 μV	0.01% + 100 μV
10 V	10 µV	0.01% + 200 μV
100 V	100 µV	0.02% + 1 mV

Capacitance Measurement Subsystem: High-Speed Capacitance Measurement Unit

Measurement accuracy is specified between any two measurement pins except the chuck connection pin. Measurement Range: 1 fF to 1.2 nF and 10 nS to 7.5 mS (1 MHz) 1 fF to 10 nF and 1 nS to 6.3 mS (100 kHz) 1 fF to 100 nF and 0.1 nS to 6.3 mS (10 kHz) $10~\mathrm{fF}$ to $100~\mathrm{nF}$ and $0.1~\mathrm{nS}$ to 63 mS (1 kHz)

Measurement Frequency:

Setting range 1 kHz to 1 MHz (34 points.

Note: Capacitance and conductance measurement accuracy is specified only when the measurement frequency is set to 1 kHz, 10 kHz, 100 kHz or 1 MHz.

Test Signal Level:

Setting range 10 mV, 30 mV, 50 mV, and 100 mV

DC Bias Range and Accuracy

Full-scale voltage range: ±10 V Setting resolution: 1 mV

Force accuracy: $\pm (0.1\%)$ of setting + 10 m)

Frequency	C Range	C Accruacy ±(% of reading + % of range)	G Range	G Accuracy ±(% of reading + % of range)
2 MHz* -	7 pF	3.2 % + [6.3 + (2.3 × Gm/88 μS)]%	88 µS	3.2% + [6.5 + (2.5 × Cm/7 pF)]%
	70 pF	2.8 % + [2.3 + (1.9×Gm/880 μS)]%	880 µS	2.8% + [2.4 + (2.1 × Cm/70 pF)]%
	10 pF*	$0.8\% + [1.1 + (0.6 \times \text{Gm}/63 \mu\text{S})]\%$	63 µS*	0.8% + [1.1 + (0.6 × Cm/10 pF)]%
1 MHz	100 pF	0.7% + [0.4 + (0.5×Gm/630 μS)]%	630 µS	0.7% + [0.4 + (0.5 × Cm/100 pF)]%
	1 nF	1.5% + [0.3 + (2.1 × Gm/6.3 mS)]%	6.3 mS	1.5% + [0.3 + (2.2 × Cm/1 nF)]%
	10 pF*	$0.4\% + [1.1 + (0.3 \times \text{Gm}/6.3 \mu\text{S})]\%$	6.3 µS*	$0.4\% + [1.1 + (0.4 \times Cm/10 \text{ pF})]\%$
100 kHz	100 pF	$0.2\% + [0.4 + (0.2 \times \text{Gm}/63 \mu\text{S})]\%$	63 µS	0.2% + [0.4 + (0.2 × Cm/100 pF)]%
	1 nF	0.2% + [0.3 + (0.4×Gm/630 μS)]%	630 µS	0.2% + [0.3 + (0.4 × Cm/1 nF)]%
	10 nF	0.5% + [0.3 + (1.0 × Gm/6.3 mS)]%	6.3 mS	0.5% + [0.3 + (1.0 × Cm/10 nF)]%
	100 pF	$0.3\% + [0.2 + (0.3 \times \text{Gm}/6.3 \mu\text{S})]\%$	6.3 µS	0.3% + [0.2 + (0.3 × Cm/100 pF)]%
10	1 nF	$0.2\% + [0.2 + (0.2 \times \text{Gm}/63 \mu\text{S})]\%$	63 µS	0.2% + [0.2 + (0.2 × Cm/1 nF)]%
10 kHz -	10 nF	0.2% + [0.2 + (0.2×Gm/630 μS)]%	630 µS	$0.2\% + [0.2 + (0.2 \times Cm/10 nF)]\%$
	100 nF	0.3% + [0.2 + (1.0 × Gm/6.3 mS)]%	6.3 mS	0.7% + [0.2 + (0.7 × Cm/100 nF)]%
	100 pF*	0.3% + [0.4 +(0.3×Gm/0.63 μS)]%	0.63 µS*	0.3% + [0.4 + (0.3 × Cm/100 pF)]%
1 kHz -	1 nF	0.3% + [0.1 + (0.3×Gm/6.3 μS)]%	6.3 µS	0.3% + [0.1 + (0.3 × Cm/1 nF)]%
	10 nF	0.3% + [0.1 + (0.3×Gm/63 µS)]%	63 µS	0.3% + [0.1 + (0.3 × Cm/10 nF)]%
	100 nF	0.3% + [0.1 + (0.3×Gm/630 μS)]%	630 µS	0.3% + [0.1 + (0.3 × Cm/100 nF)]%

C/G Measurement Range, Resolution, and Accuracy

* Supplemental Characteristics

Gm: Measured conductance

Cm: Measured capacitance

Conductance and capacitance measurements are specified under the following conditions:

Measurement frequency: 1 kHz, 10 kHz, 100 kHz, or 1 MHz

Integration time: MEDIUM or LONG

Test signal level: 30 mVrms

Stray capacitance: Mustbe under 5 pF between force and guard

Calibration and offset cancel: Specifications are valid for the data after calibration data measurement and offset canel.

Capacitance measurement accuracy of HSCMU may be affected by conducted RF field strength over 3 Vms at frequency range of 1 MHz to 20 MHz.

Measurement Accuracy (Supplemental Characteristics)

The following table shows the supplemental characteristics of the impedance (Z) and phase (θ) measurement accuracy.

		C Accuracy	
Frequency	C Range	± (% of reading + % of range)	θ Accuracy
	10 kΩ	0.8% + 1.8%	±0.26 rad
1 MHz	1 kΩ	0.7% + 0.6%	±0.02 rad
	100 Ω	1.5% + 0.5%	±0.02 rad
	100 kΩ	0.4% + 1.8%	±0.03 rad
	10 kΩ	0.2% + 0.6%	±0.01 rad
100 kHz	1 kΩ	0.2% + 0.5%	±0.01 rad
	100 Ω	0.5% + 0.5%	±0.01 rad
	100 kΩ	0.3% + 0.3%	±0.01 rad
10 kHz	10 kΩ	0.2% + 0.3%	±0.01 rad
10 KHZ	1 kΩ	0.2% + 0.3%	±0.01 rad
	100 Ω	0.3% + 0.3%	±0.01 rad
	100 kΩ	0.3% + 0.2%	±0.01 rad
1 kHz	10 k Ω	0.3% + 0.2%	±0.01 rad
	1 kΩ	0.3% + 0.2%	±0.01 rad

Pulse Force Unit

Supported Pulse Generators: 81110A and 8114A

Maximum Number of Installable **Pulse Generators:**

 $81110A \times 5$ (without 8114A) $81110A \times 4$ (with $8114A \times 1$) $81110A \times 2$ (with $8114A \times 2$)

Pulse Force Mode

Pulse Signal: 2-level and 3-level output **Burst Count:** 10^9 (max.) or infinite Output mode Normal mode or Pattern mode Normal mode All pulse generators (up to five) can force synchronously. Pattern mode All pulse generators except the master pulse generator can force synchronously (more accurate pulse width and pulse delay than normal mode).

Note: Agilent 8114A does not support pattern mode.

Load impedance

999 k Ω (default), selectable from 2.5 Ω to 999 k Ω (81110A) 999 k Ω (default), selectable from 10 Ω to 999 k Ω (8114A)

Pulse Setting Range

Pulse Period

Normal mode 81110A: Range: 350 ns to 999 s **Resolution: 4 digits** (min. 100 ps) 8114A: Range: 350 ns to 999 ms **Resolution: 3 digits** (min. 1 ns) Pattern mode 81110A: Range: 120 µs to 999 s **Resolution: 4 digits** (min. 100 ns) 8114A: Range: 120 ns to 999 ms **Resolution: 3 digits** $(min. 1 \mu s)$

Pulse Width

Normal mode 81110A: Range: 50 ns to 999 ms **Resolution: 3.5 digits** (min. 50 ps) 8114A: Range: 150 ns to 150 ms **Resolution: 3 digits** (min. 1 ns) Pattern mode 81110A in the master unit Range: 50 ns to 999 ms **Resolution: 3 digits** (min. 100 ps) 8114A in the master unit Range: 150 ns to 150 ms **Resolution: 3 digits** $(\min. 1 ns)$ 81110A in slave units Range: 100 ns to 999 ms **Resolution:** 1×10^{-n} (at $1000 \times 10^{-n} < T$ $\leq 4000 \times 10^{-n}$ $2\times10^{\text{-n}}$ (at 4000 $\times10^{\text{-n}}$ < T $\leq 8000 \times 10^{-n}$ 2.5×10^{-n} (at $8000 \times 10^{-n} < T$ $\leq 10000 \times 10^{-n}$

Pulse Force Unit (continued)

T means the maximum value of (pulse width + delay time) among all the channels. For example, if T is 250 µs, then according to the above table, the resolution is 0.1 μ s (1 \times 10^{-7}) because T= 250×10^{-6} = 2500×10^{-7} . **Pulse Delav** Normal mode 81110A Range: 0 to 998 ms **Resolution: 3.5 digits** (min. 5 ps) 8114A Range: 0 to 998 ms **Resolution: 3 digits** (min. 10 ps) Pattern mode Range: 0 to 998 ms **Resolution:** 81110A and 8114A in the master unit 3 digits (min. 10 ps) 81110A in slave units 1×10^{-n} (at $1000 \times 10^{-n} < T$ $\leq 4000 \times 10^{-n}$) $2\times10^{\text{-n}}$ (at 4000 $\times\times10^{\text{-n}}\,{}^{\rm <}\,{\rm T}$ $\leq 8000 \times 10^{-n}$) 2.5×10^{-n} (at 8000 × 10⁻ⁿ < T $\leq 10000 \times 10^{-n}$ T means pulse period specified in the Force pg subprogram. If not specified, T is the maximum value of 1.1 \times (pulse width + delay time + 30ns) among all specified PGs. **Transition Time**

20 ns to 200 ms (81110A) 65 ns (fixed) (8114A)

Pulse Level (at open load)

81110A: ±19 V (at 2 level)
±19 V (at 3 level)
Restriction for "3-level pulse with one PG" output mode: the sum of the absolute values of both amplitudes cannot exceed 20 V.
8114A: -49.9 V to +50 V (at 2 level)
-49.9 V to +50 V (at 3 level)

-49.9 V to +50 V (at 2 level) -49.9 V to +50 V (at 3 level) There is no "3-level pulse with one PG" output mode on the 81110A + 8114A: -49.9 V to +50 V (at 3 level) Pulse Level Accuracy (at open load) 81110A level: \pm ((2 % of amplitude) + 150 mV) 8114A amplitude: \pm ((2 % of amplitude) + 200 mV) 8114A baseline: \pm ((2 % of baseline) + (1 % of amplitude)+ 200 mV) Pulse Shape Accuracy (at 50 Ω load impedance) 81110A width: \pm (3% of setting + 2 ns) or $\pm (0.5\% \text{ of setting} + 2 \text{ ns})^*$ (in normal mode, width ≥ 50 ns) 81110A delay: \pm (3% of setting + 1 ns) $\pm (0.5\% \text{ of setting} + 1 \text{ ns})^*$ (in normal mode, width ≥ 50 ns) 81110A transition: (-10% of setting) to (+10% ofsetting + 20 ns) (transition time ≥ 20 ns) 81110A overshoot: \pm (5% of amplitude + 20 mV) (transition time ≥ 20 ns) *Supplemental characteristics after timing calibration 8114A width: $\pm (5\% \text{ of setting } + 3.5 \text{ ns})$ (width ³ 200 ns) $\pm (5\% \text{ of setting } + 6.0 \text{ ns})$ (width ³ 150 ns) 8114A delay: \pm (5% of setting + 1 ns) 8114A transition: 65 ns ± 20 ns 8114A overshoot:

Agilent 8114A because it has

only one Output.

± (5% of amplitude + 50 mV)

Pulse Shape Accuracy (at 5 kΩ load impedance: reference data) Agilent 81110A overshoot/ ringing: ± (5% of amplitude + 20 mV) 8114A overshoot/ringing: (-8% of amplitude) to (+4% of amplitude) 81110A transition time: ±(10% of setting + 5 ns)

 \pm (10% of setting + 5 ns) 8114A transition time: 56 ns \pm 5 ns

Skew between pins: ± 10 ns

System Controller

Supported Computers HP Visualize workstation C 3600, C3700B, C3750 **Operating System** HP-UX 11i BASIC/UX (C.08.04), SICL (11i-2.1) or C/ANSI C, SICL **Required Memory** 256 MB is recommended **Required Disk** 8 GB **Required GP-IB Interfaces** Agilent recommends two external GP-IB interface cards, one for instruments controlled by 4073B TIS commands (e.g., 3458A) and another for an automatic wafer prober System Software Standard 4073B software provides the following capabilities: System Management Control of subsystems (TIS Library) Parameter measurement utility (PARA Library) **Off-line** debugging

Interactive Debugging Panel (IDP: Includes Test Algorithm Code Generating Function) Probing pattern generation and

wafer maps display (PPG, MAP)

Prober Control Library (Sample program): Electroglas, TEL, and TSK

Application program (Sample program): Flash memory cell evaluation, Charge pumping method

Automatic Diagnostics

Agilent Semiconductor Process Evaluation Core Software (SPECS)

Agilent SPECS is a test shell environment for the Agilent 4070 Series.

Input

User interaction occurs via a windows-based graphical interface with spreadsheet-like operation.

Test plans require simple specifications: wafer, die, test, and probe.

Customization

Agilent supplies basic development, engineering, and operator test shell frameworks, which users can tailor or modify to create entirely new frameworks.

Analysis & Output

All data is output into a flat ASCII file which users can manipulate to allow for input into database software. In addition, the data management structure supports x-y graphs, histograms, and wafer maps.

UNIX

Users have full access to the UNIX environment from within the test shell.

General Specifications

Accuracy is specified at: Temperature: 23° C ± 5° C Humidity: 5% to 70% RH¹ Warm up: at least 40 min. Self-calibration: Within one hour after calibration Integration Time: Medium or longer

¹5% to 60% RH (no condensation) for isolation resistance of low current port. Note: Temperature change after calibration must be less than 3° C.

Power Requirement

Nominal Line Voltage²	Allowable Voltage Range	Required Maximum Current
200 Vac	180 - 220 Vac	20 A
208 Vac	188 - 228 Vac	24 A
220 Vac	198 - 242 Vac	20 A
240 Vac	216 - 252 Vac	20 A

² Line frequency must be 48 Hz to 63 Hz.

Operating Temperature Range: 5°C to 30°C Operating Humidity range: 5% to 70% (no condensation) Storage Temperature Range: -20°C to 50°C (< 80% RH, no condensation) Warm up time: At least 40 minutes

Regulatory and Standard Compliance:

EMC: EMC Directive 89/336/EEC, 93/68/EEC EN61326-1 **ICES-001** AS/NZS 2064.1 Safety: Low Voltage Directive 73/23/ EEC, 93/68/EEC EN61010-1 CSA C22.2 No.1010.1 UL3111-1 SEMI S2-0200/S8-0999 **Certification marking** CE, CSA, NRTL/C, C-tick, ICES/ **NMB-001**

Dimensions

System Cabinet: 600 mm (W) by 900 mm (D) by 1600 mm (H) Testhead: 640 mm (W) by 642 mm (D) by 400 mm (H)

Weight

System Cabinet: 235 kg (including 3458A, 81110A × 4, 8114A and system controller) Testhead: 75 kg (including 4 SMUs,

HSCMU and 48 pins)

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